TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS181D

CD54/74HC367, CD54/74HCT367, CD54/74HC368, CD74HCT368

November 1997 - Revised October 2003

High-Speed CMOS Logic Hex Buffer/Line Driver, Three-State Non-Inverting and Inverting

Features

- Buffered Inputs
- High Current Bus Driver Outputs
- Two Independent Three-State Enable Controls
- Typical Propagation Delay t_{PLH}, t_{PHL} = 8ns at V_{CC} = 5V, C_L = 15pF, T_A = 25^oC
- Fanout (Over Temperature Range)
 - Standard Outputs..... 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, II \leq 1 μA at VOL, VOH

Description

The 'HC367, 'HCT367, 'HC368, and CD74HCT368 silicon gate CMOS three-state buffers are general purpose high-speed non-inverting and inverting buffers. They have high drive current outputs which enable high speed operation even when driving large bus capacitances. These circuits possess the low power dissipation of CMOS circuitry, yet have speeds comparable to low power Schottky TTL circuits. Both circuits are capable of driving up to 15 low power Schottky inputs.

The 'HC367 and 'HCT367 are non-inverting buffers, whereas the 'HC368 and CD74HCT368 are inverting buffers. These devices have two output enables, one enable (OE1) controls 4 gates and the other (OE2) controls the remaining 2 gates.

The 'HCT367 and CD74HCT368 logic families are speed, function and pin compatible with the standard LS logic family.

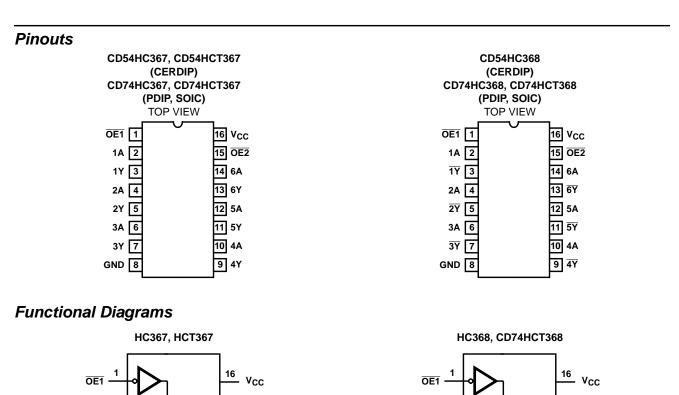
Ordering Information

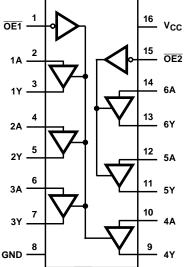
PART NUMBER	TEMP. RANGE (^o C)	PACKAGE
CD54HC367F3A	-55 to 125	16 Ld CERDIP
CD54HC368F3A	-55 to 125	16 Ld CERDIP
CD54HCT367F3A	-55 to 125	16 Ld CERDIP
CD74HC367E	-55 to 125	16 Ld PDIP
CD74HC367M	-55 to 125	16 Ld SOIC
CD74HC367MT	-55 to 125	16 Ld SOIC
CD74HC367M96	-55 to 125	16 Ld SOIC
CD74HC368E	-55 to 125	16 Ld PDIP
CD74HC368M	-55 to 125	16 Ld SOIC
CD74HC368MT	-55 to 125	16 Ld SOIC
CD74HC368M96	-55 to 125	16 Ld SOIC
CD74HCT367E	-55 to 125	16 Ld PDIP
CD74HCT367M	-55 to 125	16 Ld SOIC
CD74HCT367MT	-55 to 125	16 Ld SOIC
CD74HCT367M96	-55 to 125	16 Ld SOIC
CD74HCT368E	-55 to 125	16 Ld PDIP
CD74HCT368M	-55 to 125	16 Ld SOIC
CD74HCT368MT	-55 to 125	16 Ld SOIC
CD74HCT368M96	-55 to 125	16 Ld SOIC

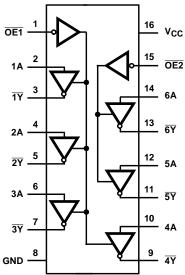
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures. Copyright © 2003, Texas Instruments Incorporated

CD54/74HC367, CD54/74HCT367, CD54/74HC368, CD74HCT368







TRUTH TABLE

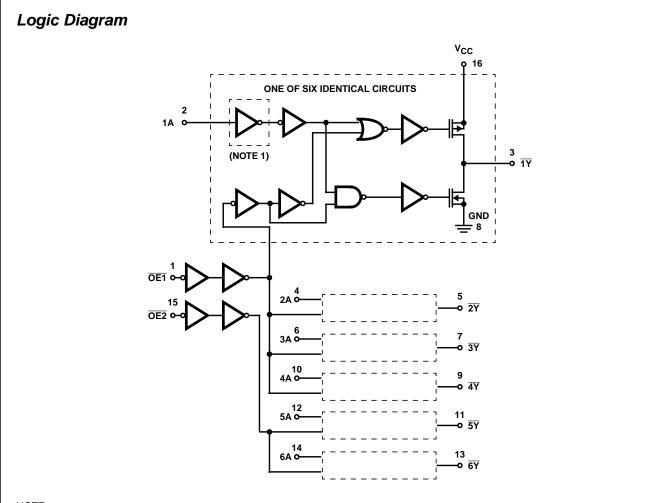
INP	UTS	ITUO ()	PUTS ()
ŌĒ	Α	HC/HCT367	HC/HCT368
L	L	L	Н
L	Н	Н	L
Н	Х	(Z)	(Z)

H = High Voltage Level

L = Low Voltage Level

X = Don't Care

Z = High Impedance (OFF) State



NOTE:

1. Inverter not included in HC/HCT367

FIGURE 1. LOGIC DIAGRAM FOR THE HC/HCT367 AND HC/HCT368 (OUTPUTS FOR HC/HCT367 ARE COMPLEMENTS OF THOSE SHOWN, i.e., 1Y, 2Y, ETC.)

Absolute Maximum Ratings

DC Supply Voltage, V _{CC}
DC Input Diode Current, I _{IK}
For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, I _{OK}
For $V_0 < -0.5V$ or $V_0 > V_{CC} + 0.5V$
DC Drain Current, per Output, I _O
For -0.5V < V _O < V _{CC} + 0.5V±35mA
DC V _{CC} or Ground Current, I _{CC} ±50mA

Operating Conditions

Temperature Range, T_A
Supply Voltage Range, V _{CC}
HC Types
HCT Types4.5V to 5.5V
DC Input or Output Voltage, VI, VO 0V to VCC
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

Thermal Information

Thermal Resistance (Typical, Note 2)	θ _{JA} (^o C/W)
E (PDIP) Package	
M (SOIC) Package	73
Maximum Junction Temperature	
Maximum Storage Temperature Range	65 ⁰ C to 150 ⁰ C
Maximum Lead Temperature (Soldering 10s)	
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			ST ITIONS			25 ⁰ C		-40°C 1	ГО 85 ⁰ С	-55°С Т	O 125 ⁰ C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX		
HC TYPES													
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V	
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V	
				6	4.2	-	-	4.2	-	4.2	-	V	
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V	
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V	
				6	-	-	1.8	-	1.8	-	1.8	V	
High Level Output	V _{OH}	V _{IH} or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V	
Voltage CMOS Loads			V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
CINOS LOAUS			-0.02	6	5.9	-	-	5.9	-	5.9	-	V	
High Level Output	1		-6	4.5	3.98	-	-	3.84	-	3.7	-	V	
Voltage TTL Loads			-7.8	6	5.48	-	-	5.34	-	5.2	-	V	
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	V	
Voltage CMOS Loads		VIL	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V	
emee Loads			0.02	6	-	-	0.1	-	0.1	-	0.1	V	
Low Level Output	1		6	4.5	-	-	0.26	-	0.33	-	0.4	V	
Voltage TTL Loads			7.8	6	-	-	0.26	-	0.33	-	0.4	V	
Input Leakage Current	lı	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μA	
Quiescent Device Current	ICC	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μA	
Three-State Leakage Current	I _{OZ}	V _{IL} or V _{IH}	V _O = V _{CC} or GND	6	-	-	±0.5	-	±5.0	-	±10	μA	

CD54/74HC367, CD54/74HCT367, CD54/74HC368, CD74HCT368

			ST ITIONS			25 ⁰ C		-40 ⁰ C 1	O 85°C	-55 ⁰ C T	0 125 ⁰ C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	VIL	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} to GND	0	5.5	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	∆I _{CC} (Note 3)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μA
Three-State Leakage Current	I _{OZ}	V _{IL} or V _{IH}	V _O = V _{CC} or GND	5.5	-	-	±0.5	-	±5.0	-	±10	μA

DC Electrical Specifications (Continued

NOTE:

3. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS				
OE1	0.6				
All Others	0.55				

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360µA max at 25^oC.

Switching Specifications Input t_r , $t_f = 6ns$

		TEST		25 ⁰ C		-40°C TO 85°C	-55 ⁰ C TO 125 ⁰ C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
HC TYPES	_				_			
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	105	130	160	ns
Data to Outputs HC/HCT367			4.5	-	21	26	32	ns
			6	-	18	24	27	ns
		C _L = 15pF	5	8	-	-	-	ns

		TEST		25	^o C	-40°C TO 85°C	-55 ⁰ C TO 125 ⁰ C		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS	
Propagation Delay,	t _{PLH} , t _{PHL}	$C_L = 50 pF$	2	-	105	130	160	ns	
Data to Outputs HC/HCT368			4.5	-	21	26	32	ns	
			6	-	18	24	27	ns	
		C _L = 15pF	5	9	-	-	-	ns	
Propagation Delay,	t _{PLH} , t _{PHL}	$C_L = 50 pF$	2	-	150	190	225	ns	
Output Enable and Disable to Outputs			4.5	-	30	38	45	ns	
			6	-	26	33	38	ns	
		C _L = 15pF	5	12	-	-	-	ns	
Output Transition Time	t _{TLH} , t _{THL}	$C_L = 50 pF$	2	-	60	75	90	ns	
			4.5	-	12	15	18	ns	
			6	-	10	13	15	ns	
Input Capacitance	Cl	-	-	-	10	10	10	pF	
Three-State Output Capacitance	CO	-	-	-	20	20	20	pF	
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	40	-	-	-	pF	
HCT TYPES									
Propagation Delay,	t _{PLH} , t _{PHL}	$C_L = 50 pF$	4.5	-	25	31	38	ns	
Data to Outputs HC/HCT367		C _L = 15pF	5	9	-	-	-	ns	
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	30	38	45	ns	
Data to Outputs HC/HCT368		C _L = 15pF	5	11	-	-	-	ns	
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	35	44	53	ns	
Output Enable and Disable to Outputs		C _L = 15pF	5	14	-	-	-	ns	
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	12	15	18	ns	
Input Capacitance	C _{IN}	-	-	-	10	10	10	pF	
Three-State Capacitance	CO	-	-	-	20	20	20	pF	
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	42	-	-	-	pF	

Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

NOTES:

4. $C_{\mbox{PD}}$ is used to determine the dynamic power consumption, per buffer.

5. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = Input Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

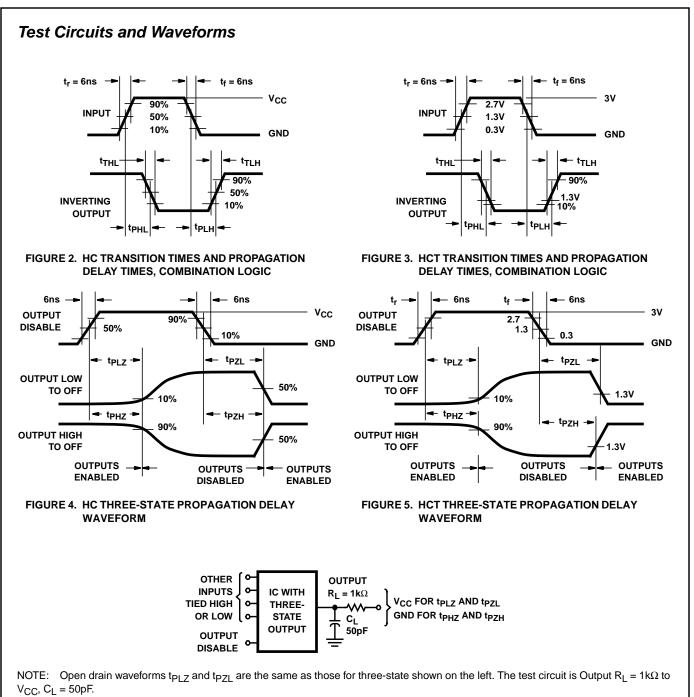


FIGURE 6. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT

9-Oct-2007

PACKAGING INFORMATION

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Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finisl	n MSL Peak Temp ⁽³
5962-9070601MEA	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
9070601MEAS2035	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI
CD54HC367F3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC368F	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC368F3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT367F3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD74HC367E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC367EE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC367M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC367M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC367M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC367M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC367ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC367MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC367MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC367MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC367MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC368E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC368EE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC368M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC368M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC368M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC368M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC368ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC368MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC368MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC368MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN

PACKAGE OPTION ADDENDUM

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9-Oct-2007

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp
CD74HC368MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT367E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT367EE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT367M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT367M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT367M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT367M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT367ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT367MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT367MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT367MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT367MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT368E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT368EE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT368M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT368M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT368M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT368M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT368ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT368MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT368MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT368MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
CD74HCT368MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. **PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.



OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



All dimensions are nominal												
Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC367M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC368M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT367M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT368M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1



PACKAGE MATERIALS INFORMATION

19-Mar-2008



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC367M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HC368M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HCT367M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HCT368M96	SOIC	D	16	2500	333.2	345.9	28.6

J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.

Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.

E. Reference JEDEC MS-012 variation AC.



D(R-PDSO-G16)



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



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